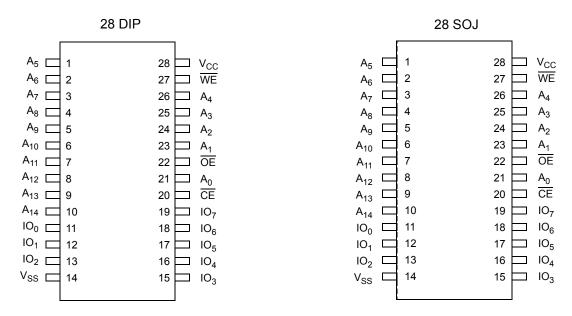
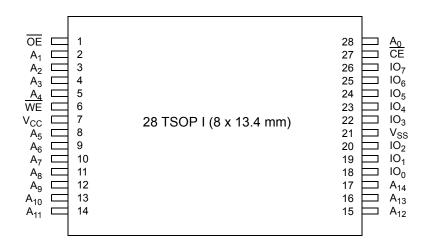


## **Pin Layout and Specifications**





Document #: 001-06435 Rev. \*D



## **Pin Description**

Pin	Туре	Description	DIP	SOJ	TSOP I
A <sub>X</sub>	Input	Address Inputs	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 21, 23, 24, 25, 26	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 21, 23, 24, 25, 26	2, 3, 4, 5, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 28
CE	Control	Chip Enable	20	20	27
IO <sub>X</sub>	Input or Output	Data Input Outputs	11, 12, 13, 15, 16, 17, 18, 19	11, 12, 13, 15, 16, 17, 18, 19	18, 19, 20, 22, 23, 24, 25, 26
ŌE	Control	Output Enable	22	22	1
V <sub>CC</sub>	Supply	Power (5.0V)	28	28	7
V <sub>SS</sub>	Supply	Ground	14	14	21
WE	Control	Write Enable	27	27	6

## **Truth Table**

CE	OE	WE	IOx	IOx Mode	
Н	X	X	High-Z	High-Z Deselect/Power Down	
L	L	Н	Data Out	Read	Active (I <sub>CC</sub> )
L	Х	L	Data In	Write	Active (I <sub>CC</sub> )
L	Н	Н	High-Z	Selected, Outputs Disabled	Active (I <sub>CC</sub> )

# **Maximum Ratings**

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Parameter	Description	Value	Unit
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
T <sub>AMB</sub>	Ambient Temperature with Power Applied (that is, case temperature)	-55 to +125	°C
V <sub>CC</sub>	Core Supply Voltage Relative to V <sub>SS</sub>	-0.5 to +7.0	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Voltage Applied to Any Pin Relative to V <sub>SS</sub>	$-0.5$ to $V_{CC} + 0.5$	V
l <sub>out</sub>	Output Short-Circuit Current	20	mA
V <sub>ESD</sub>	Static Discharge Voltage (in accordance with MIL-STD-883, Method 3015)	> 2001	V
I <sub>LU</sub>	Latch-up Current	> 200	mA

# **Operating Range**

Range	Ambient Temperature (T <sub>A</sub> )	Voltage Range (V <sub>CC</sub> )
Commercial	0°C to 70°C	5.0V ± 10%
Industrial	–40°C to 85°C	5.0V ± 10%
Automotive-A		

Document #: 001-06435 Rev. \*D Page 3 of 14



#### **DC Electrical Characteristics**

Over the Operating Range (-12, -15) [2]

Doromotor	Description	Condition	Dower		-12		<b>-15</b>	l lmi4
Parameter	Description	Condition	Power	Min	Max	Min	Max	Unit
V <sub>IH</sub>	Input HIGH Voltage		-	2.2	V <sub>CC</sub> + 0.3	2.2	V <sub>CC</sub> + 0.3	V
V <sub>IL</sub>	Input LOW Voltage		-	-0.5	0.8	-0.5	0.8	V
V <sub>OH</sub>	Output HIGH Voltage	$V_{CC}$ = Min, $I_{OH}$ = -4.0 mA	-	2.4	-	2.4	-	V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = 8.0 mA	-	-	0.4	_	0.4	V
I <sub>CC</sub>	V <sub>CC</sub> Operating Supply Current	$V_{CC}$ = Max, $I_{OUT}$ = 0 mA, f = $F_{max}$ = 1/ $t_{RC}$	-	-	85	-	80	mA
I <sub>SB1</sub>	Automatic CE Power		-	-	30	_	30	mA
	Down Current TTL Inputs	$V_{IN} \ge V_{IH}$ or $V_{IN} \le V_{IL}$ , $f = F_{max}$	L	-	10	-	10	mA
I <sub>SB2</sub>		Max $V_{CC}$ , $\overline{CE} \ge V_{CC} - 0.3V$ ,	-	_	10	_	10	mA
	Inputs	$V_{IN} \ge V_{CC} - 0.3V$ , or $V_{IN} \le 0.3V$ , f = 0	L	-	500	-	500	μΑ
I <sub>OZ</sub>	Output Leakage Current	$GND \leq V_I \leq V_{CC}, \ Output \ Disabled$	-	<b>-</b> 5	+5	<b>-</b> 5	+5	μА
I <sub>IX</sub>	Input Leakage Current	$GND \leq V_I \leq V_CC$	ı	<b>–</b> 5	+5	<b>–</b> 5	+5	μА

# **DC Electrical Characteristics**

Over the Operating Range (-20, -25) [2]

Parameter	Description	Condition	Power		-20		Unit	
Parameter	Description	Condition	Power	Min	Max	Min	Max	Ollit
V <sub>IH</sub>	Input HIGH Voltage		-	2.2	V <sub>CC</sub> + 0.3	2.2	V <sub>CC</sub> + 0.3	V
$V_{IL}$	Input LOW Voltage		-	-0.5	0.8	-0.5	0.8	V
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min, I <sub>OH</sub> = -4.0 mA	-	2.4	_	2.4	-	V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = 8.0 mA	-	_	0.4	_	0.4	V
I <sub>CC</sub>	V <sub>CC</sub> Operating Supply Current	$V_{CC}$ = Max, $I_{OUT}$ = 0 mA, f = $F_{max}$ = 1/ $t_{RC}$	-	-	75	-	75	mA
I <sub>SB1</sub>	Automatic CE Power	$\operatorname{Max} V_{CC}, \overline{CE} \ge V_{IH},$	-	_	30	_	30	mA
	Down Current TTL Inputs	$V_{IN} \ge V_{IH}$ or $V_{IN} \le V_{IL}$ , $f = F_{max}$	L	-	10	_	10	mA
I <sub>SB2</sub>		Max $V_{CC}$ , $\overline{CE} \ge V_{CC} - 0.3V$ ,	-	_	10	_	10	mA
	Down Current CMOS Inputs	$V_{IN} \ge V_{CC} - 0.3V$ , or $V_{IN} \le 0.3V$ , f = 0	L	-	500	-	500	μА
I <sub>OZ</sub>	Output Leakage Current	$GND \leq Vi \leq V_{CC}, \ Output \ Disabled$	-	<b>-</b> 5	+5	<b>–</b> 5	+5	μА
I <sub>IX</sub>	Input Leakage Current	$GND \leq Vi \leq V_{CC}$	-	<b>–</b> 5	+5	<b>–</b> 5	+5	μА

#### Note

Document #: 001-06435 Rev. \*D Page 4 of 14

<sup>2.</sup>  $V_{IL}$  (min) = -2.0V for pulse durations of less than 20 ns.



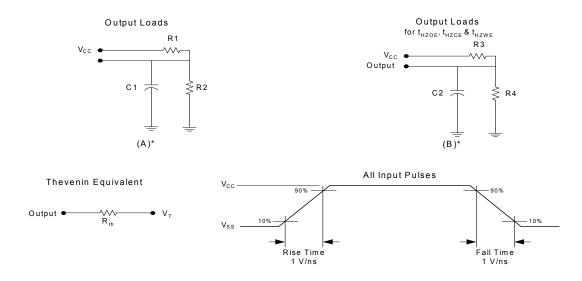
## Capacitance [3]

Parameter	Description	Conditions	Max	Unit
C <sub>IN</sub>	Input Capacitance	$T_A = 25^{\circ}C$ , $f = 1$ MHz, $V_{CC} = 5.0V$	8	pF
C <sub>OUT</sub>	Output Capacitance		8	

## Thermal Resistance [3]

Parameter	Description	Conditions	TSOP I	SOJ	DIP	Unit
U/A	(junction to ambient)	Still air, soldered on a 3 × 4.5 square inch, two–layer printed	88.6	79	69.33	°C/W
30	Thermal Resistance (junction to case)	circuit board	21.94	41.42	31.62	

#### **AC Test Loads**



\* including scope and jig capacitance

#### **AC Test Conditions**

Parameter	Description	Nom	Unit
C1	Capacitor 1	30	pF
C2	Capacitor 2	5	
R1	Resistor 1	480	Ω
R2	Resistor 2	255	
R3	Resistor 3	480	
R4	Resistor 4	255	
R <sub>TH</sub>	Resistor Thevenin	167	
V <sub>TH</sub>	Voltage Thevenin	1.73	V

#### Note

Document #: 001-06435 Rev. \*D Page 5 of 14

<sup>3.</sup> Tested initially and after any design or process change that may affect these parameters.



#### AC Electrical Characteristics [4]

Downwoodow	Description		_	12	-15		-20		-25		Unit
Parameter			Min	Max	Min	Max	Min	Max	Min	Max	Oilit
t <sub>RC</sub>	Read Cycle Time	;	12	_	15	_	20	_	25	_	ns
t <sub>AA</sub>	Address to Data	Valid	_	12	_	15	_	20	_	25	ns
t <sub>OHA</sub>	Data Hold from A Change	Address	3	-	3	-	3	-	3	-	ns
t <sub>ACE</sub>	CE to Data Valid		_	12	_	15	_	20	_	25	ns
t <sub>DOE</sub>	OE to Data Valid	Ind'I/Com'I	_	5	_	7	_	9	_	9	ns
		Automotive-A	_	6	_	_	_	_	_	_	1
t <sub>LZOE</sub>	OE to Low-Z [5]		0	_	0	_	0	_	0	_	ns
t <sub>HZOE</sub>	OE to High-Z [5, 6	6]	_	5	_	7	_	9	_	9	ns
t <sub>LZCE</sub>	CE to Low-Z [5]		3	_	3	_	3	_	3	_	ns
t <sub>HZCE</sub>	CE to High-Z [5, 6	6]	_	5	_	7	-	9	_	9	ns
t <sub>PU</sub>	CE to Power Up		0	_	0	_	0	-	0	_	ns
t <sub>PD</sub>	CE to Power Dov	wn	_	12	_	15	_	20	_	20	ns
t <sub>WC</sub>	Write Cycle Time	· [7]	12	_	15	_	20	_	25	_	ns
t <sub>SCE</sub>	CE to Write End		9	-	10	-	15	-	15	-	ns
t <sub>AW</sub>	Address Setup to	Write End	9	-	10	-	15	-	15	-	ns
t <sub>HA</sub>	Address Hold fro	m Write End	0	_	0	-	0	-	0	_	ns
t <sub>SA</sub>	Address Setup to	Write Start	0	_	0	-	0	-	0	_	ns
t <sub>PWE</sub>	WE Pulse Width		8	-	9	-	15	-	15	-	ns
t <sub>SD</sub>	Data Setup to Wi	rite End	8	_	9	_	10	-	10	_	ns
t <sub>HD</sub>	Data Hold from V	Vrite End	0	_	0	_	0	-	0	_	ns
t <sub>HZWE</sub>	WE LOW to High	n-Z <sup>[5, 6]</sup>	_	7	_	7	-	10	_	10	ns
t <sub>LZWE</sub>	WE HIGH to Low	v-Z <sup>[5]</sup>	3	_	3	_	3	_	3	_	ns

#### Data Retention Characteristics [8]

Parameter	Description	Condition	Min	Max	Unit
$V_{DR}$	V <sub>CC</sub> for Data Retention		2.0	_	V
I <sub>CCDR</sub>		$V_{CC} = V_{DR} = 2.0V, \overline{CE} \ge V_{CC} - 0.3V,$	_	150	μΑ
t <sub>CDR</sub>	Chip Deselect to Data Retention Time	$V_{IN} \ge V_{CC} - 0.3V$ or $V_{IN} \le 0.3V$	0	-	ns
t <sub>R</sub>	Operation Recovery Time		200	-	μS

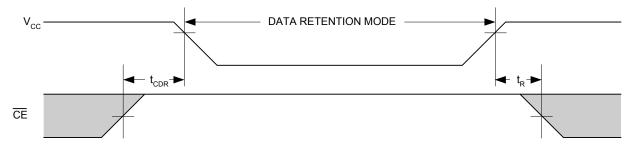
- Test Conditions are based on a transition time of 3 ns or less and timing reference levels of 1.5V, and input pulse levels of 0 to 3.0V.
   At any given temperature and voltage condition, t<sub>HZCE</sub> is less than t<sub>LZOE</sub>, t<sub>HZOE</sub> is less than t<sub>LZOE</sub>, and t<sub>HZWE</sub> is less than t<sub>LZWE</sub> for any given device.
- that y given temperature and votage centation, the content of the co

8. L-version only.

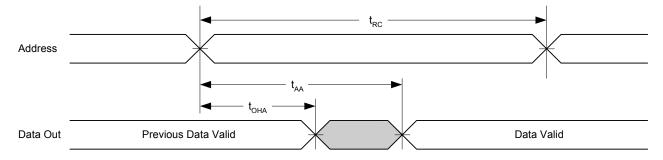


## **Timing Waveforms**

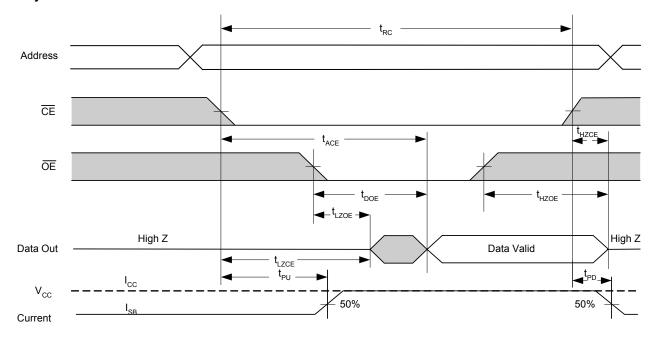
#### **Data Retention Waveform**



## Read Cycle 1 [9, 10]



# Read Cycle 2 [11, 12]



#### Notes

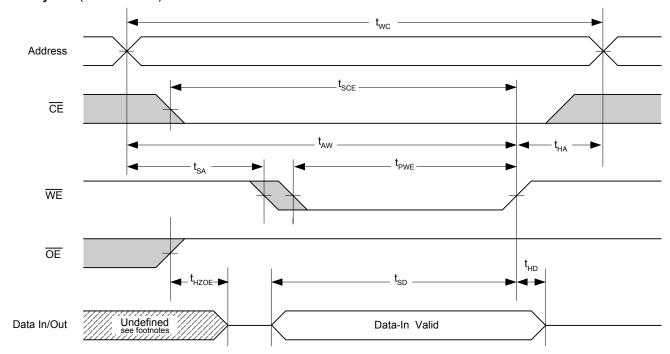
- 9. Device is continuously selected.  $\overline{OE} = V_{IL} = \overline{CE}$ .
- 10.  $\overline{\text{WE}}$  is HIGH for read cycle.
- 11. This cycle is  $\overline{OE}$  controlled and  $\overline{WE}$  is HIGH read cycle.
- 12. Address valid before or similar with  $\overline{\text{CE}}$  transition LOW.

Document #: 001-06435 Rev. \*D

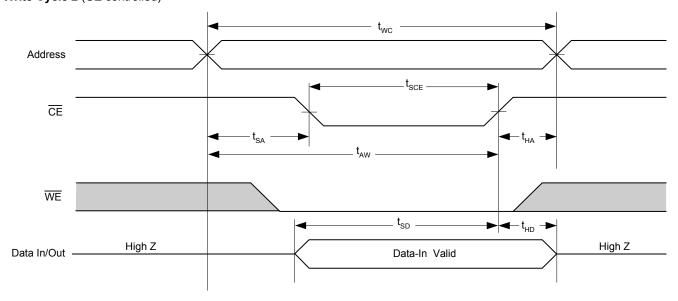


## Timing Waveforms (continued)

# Write Cycle 1 (WE controlled) [13, 14, 15]



# Write Cycle 2 ( $\overline{\text{CE}}$ controlled) [14, 16, 17]



#### Notes

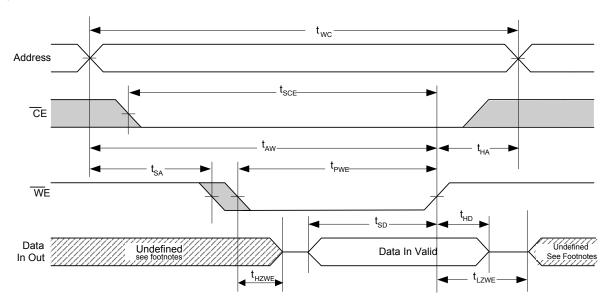
- 13. This cycle is  $\overline{\text{WE}}$  controlled,  $\overline{\text{OE}}$  is HIGH during write.
- 14. Data in and/or out is high impedance if  $\overline{OE} = V_{IH}$ .
- 15. During this period the IOs are in output state and input signals must not be applied.
- 16. This cycle is  $\overline{\text{CE}}$  controlled.
- 17. If  $\overline{\text{CE}}$  goes HIGH simultaneously with  $\overline{\text{WE}}$  going HIGH, the output remains in a high impedance state.

Document #: 001-06435 Rev. \*D



## Timing Waveforms (continued)

Write Cycle 3 ( $\overline{\text{WE}}$  controlled,  $\overline{\text{OE}}$  low) [18]



#### Note

<sup>18.</sup> The cycle is  $\overline{\text{WE}}$  controlled,  $\overline{\text{OE}}$  LOW. The minimum write cycle time is the sum of  $t_{\text{HZWE}}$  and  $t_{\text{SD}}$ .

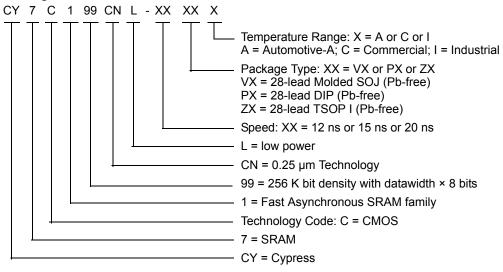


## **Ordering Information**

Contact local sales representative regarding availability of these parts.

Speed (ns)	Ordering Code	Package Diagram	Package Type	Power Option	Operating Range
12	CY7C199CN-12VXA	51-85031	28-Lead (300-Mil) Molded SOJ, Pb-free	Standard	Automotive-A
15	CY7C199CN-15PXC	51-85014	28 DIP (6.9 x 35.6 x 3.5 mm), Pb-free	Standard	Commercial
	CY7C199CN-15VXC	51-85031	28-Lead (300-Mil) Molded SOJ, Pb-free	Standard	Commercial
	CY7C199CNL-15VXI	51-85031	28-Lead (300-Mil) Molded SOJ, Pb-free	Low Power	Industrial
20	CY7C199CN-20ZXI	51-85071	28 TSOP I (8 x 13.4 mm), Pb-free	Standard	Industrial

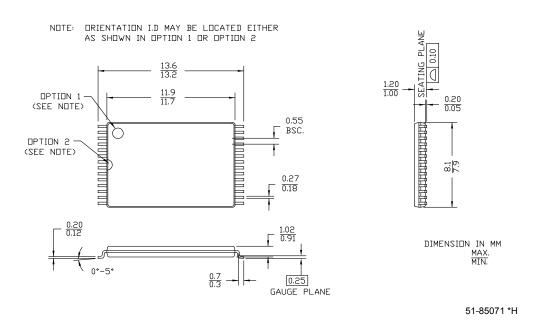
#### **Ordering Code Definitions**





## **Package Diagrams**

Figure 1. 28-pin TSOP I (8 x 13.4 mm), 51-85071



[+] Feedback

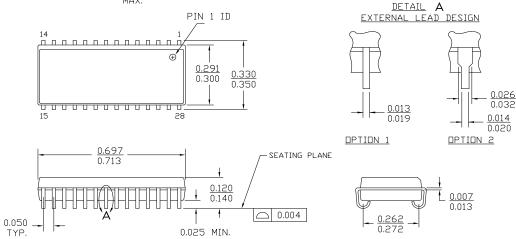


# Package Diagrams (continued)

Figure 2. 28-pin (300 Mil) Molded SOJ, 51-85031

#### NOTE :

- 1. JEDEC STD REF MO088
- 2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.006 in (0.152 mm) PER SIDE
- 3. DIMENSIONS IN INCHES MIN. MAX.

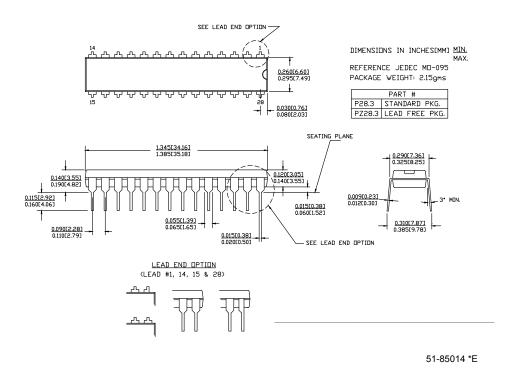


51-85031 \*D



## Package Diagrams (continued)

Figure 3. 28-pin (300 Mil) PDIP, 51-85014



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Document #: 001-06435 Rev. \*D

[+] Feedback



## **Document History Page**

Document Title: CY7C199CN, 256K (32K x 8) Static RAM Document Number: 001-06435				
REV.	ECN No.	Issue Date	Orig. of Change	Description of Change
**	430363	See ECN	NXR	New Data Sheet
*A	684342	See ECN	VKN	Added Automotive-A Information Updated Ordering Information Table
*B	839904	See ECN	VKN	Added t <sub>DOE</sub> spec for Automotive-A part in AC Electrical characteristics table
*C	2896044	03/19/2010	NXR	Updated Ordering Information Table Updated Package Diagram
*D	3108898	12/13/2010	PRAS	Added Ordering Code Definitions.

[+] Feedback